MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet





SOT-23

Features

- 300 Watts peak pulse power (tp = $8/20\mu$ s
-) Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection two data lines:
- IEC 61000-4-2 ±30kV contact ±30kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 15A (8/20μs)

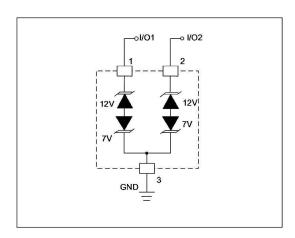
Mechanical Data

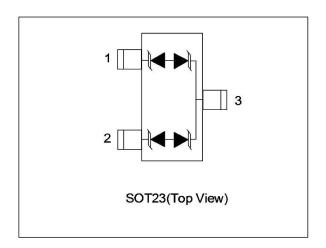
- SOT-23 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Applications

- Dataline
- Automatic Teller Machines
- Net works
- Power line

Schematic & PIN Configuration







Absolute Maximum Rating

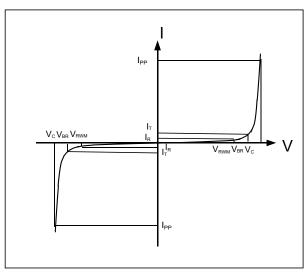
Rating	Symbol	Value	Units	
Peak Pulse Power (t _p =8/20μs)	P _{PP}	300	Watts	
Peak Pulse Current (t _p =8/20μs) (note1)	I_{pp}	18	A	
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$ m V_{ESD}$	30 30	kV	
Lead Soldering Temperature	$T_{ m L}$	260(10seconds)	$^{\circ}$ C	
Junction Temperature	TJ	-55 to + 125	$^{\circ}$ C	
Storage Temperature	$T_{ m stg}$	-55 to + 125	°C	

Electrical Characteristics

			Pins 1 to 3 and 2 to 3 (12V TVS)			Pins 3 to 1 and 3 to 2 (7V TVS)			
Parameter	Symbol	Conditions	Min	Typical	Max	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				12			7	V
Reverse Breakdown Voltage	$V_{\scriptsize BR}$	IT=1mA	13.5		16	7.5		9.5	V
Reverse Leakage Current	Ir	VR=VRWM			1			1	μΑ
Clamping Voltage	Vc	IPP=15A,tp=8/20μs		18					V
Clamping Voltage	Vc	IPP=18A,tp=8/20μs					14		V
Junction Capacitance	Cj	$V_R = 0V, f = 1MHz$		27			35		pF

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ Ipp	
V _{RWM}	Working Peak Reverse Voltage	
IR	Maximum Reverse Leakage Current @ VRWM	
V_{BR}	Breakdown Voltage @ IT	
Iτ	Test Current	



Note:. $8/20\mu s$ pulse waveform.



Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

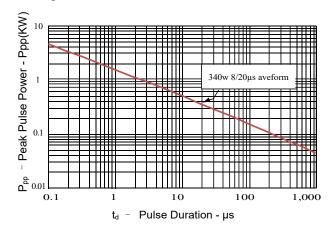


Figure 2: Power Derating Curve

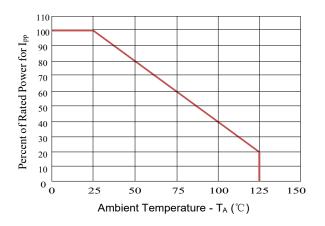


Figure3: Pulse Waveform

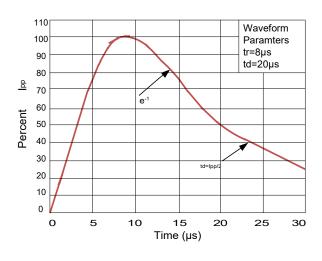
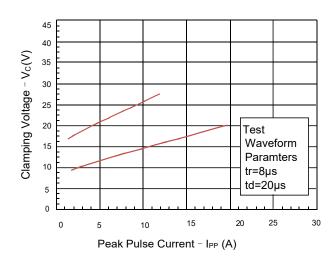
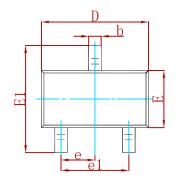


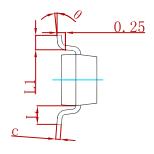
Figure 4: Clamping Voltage vs.lpp

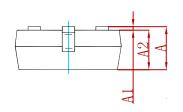


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PACKAGE MECHANICAL DATA

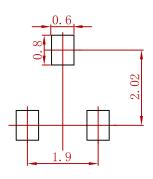






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
SDT23C712L02-MS	SOT-23	3000



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